

Plastic Darlington Complementary Silicon Power Transistors

... designed for general-purpose amplifier and low-speed switching applications.

- High DC Current Gain —
 $h_{FE} = 2000$ (Typ) @ I_C
 $= 2.0$ Adc
- Monolithic Construction with Built-in Base-Emitter Resistors to Limit Leakage Multiplication
- Choice of Packages —
 MJE700 and MJE800 series

MAXIMUM RATINGS

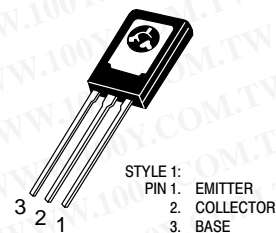
| Rating | Symbol | MJE700 MJE800 | MJE702 MJE703 MJE802 MJE803 | Unit |
|---|----------------|------------------|--------------------------------------|------------------------------|
| Collector-Emitter Voltage | V_{CEO} | 60 | 80 | Vdc |
| Collector-Base Voltage | V_{CB} | 60 | 80 | Vdc |
| Emitter-Base Voltage | V_{EB} | 5.0 | | Vdc |
| Collector Current | I_C | 4.0 | | Adc |
| Base Current | I_B | 0.1 | | Adc |
| Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | CASE 77 | | Watts W/ $^\circ\text{C}$ |
| | | 40 0.32 | | |
| Operating and Storage Junction Temperature Range | T_J, T_{stg} | -55 to +150 | | $^\circ\text{C}$ |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|--------------|---------------------------|
| Thermal Resistance, Junction to Case CASE 77 TO-220 | $R_{\theta JC}$ | 3.13 2.50 | $^\circ\text{C}/\text{W}$ |

PNP
MJE700
MJE702
MJE703
NPN
MJE800
MJE802
MJE803

**4.0 AMPERE
 DARLINGTON
 POWER TRANSISTORS
 COMPLEMENTARY
 SILICON
 40 WATT
 50 WATT**



**CASE 77-08
 TO-225AA TYPE
 MJE700-703
 MJE800-803**

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

MJE700 MJE702 MJE703 MJE800 MJE802 MJE803

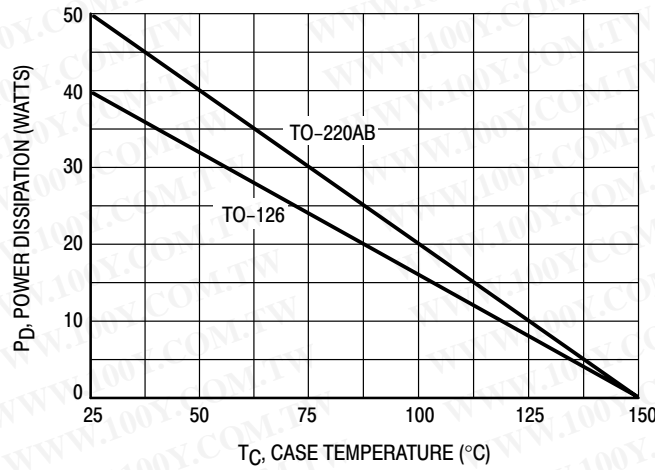


Figure 1. Power Derating

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit | |
|---|---|---------------|-------------------|-------------------|-----------------|
| OFF CHARACTERISTICS | | | | | |
| Collector–Emitter Breakdown Voltage (1) ($I_C = 50\text{ mAdc}$, $I_B = 0$) | MJE700, MJE800 MJE702, MJE703, MJE802, MJE803 | $V_{(BR)CEO}$ | 60 80 | — — | Vdc |
| Collector Cutoff Current ($V_{CE} = 60\text{ Vdc}$, $I_B = 0$) ($V_{CE} = 80\text{ Vdc}$, $I_B = 0$) | MJE700, MJE800 MJE702, MJE703, MJE802, MJE803 | I_{CEO} | — — | 100 100 | μAdc |
| Collector Cutoff Current ($V_{CB} = \text{Rated } BV_{CEO}$, $I_E = 0$) ($V_{CB} = \text{Rated } BV_{CEO}$, $I_E = 0$, $T_C = 100^\circ\text{C}$) | | I_{CBO} | — — | 100 500 | μAdc |
| Emitter Cutoff Current ($V_{BE} = 5.0\text{ Vdc}$, $I_C = 0$) | | I_{EBO} | — | 2.0 | mAdc |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain (1) ($I_C = 1.5\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) ($I_C = 4.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) | MJE700, MJE702, MJE800, MJE802 MJE703, MJE803 All devices | h_{FE} | 750 750 100 | — — — | — |
| Collector–Emitter Saturation Voltage (1) ($I_C = 1.5\text{ Adc}$, $I_B = 30\text{ mAdc}$) ($I_C = 2.0\text{ Adc}$, $I_B = 40\text{ mAdc}$) ($I_C = 4.0\text{ Adc}$, $I_B = 40\text{ mAdc}$) | MJE700, MJE702, MJE800, MJE802 MJE703, MJE803 All devices | $V_{CE(sat)}$ | — — — | 2.5 2.8 3.0 | Vdc |
| Base–Emitter On Voltage (1) ($I_C = 1.5\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) ($I_C = 2.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) ($I_C = 4.0\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$) | MJE700, MJE702, MJE800, MJE802 MJE703, MJE803 All devices | $V_{BE(on)}$ | — — — | 2.5 2.5 3.0 | Vdc |
| DYNAMIC CHARACTERISTICS | | | | | |
| Small–Signal Current Gain ($I_C = 1.5\text{ Adc}$, $V_{CE} = 3.0\text{ Vdc}$, $f = 1.0\text{ MHz}$) | | h_{fe} | 1.0 | — | — |

(1) Pulse Test: Pulse Width $\leq 300\ \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

MJE700 MJE702 MJE703 MJE800 MJE802 MJE803

R_B & R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS
 D_1 , MUST BE FAST RECOVERY TYPE, e.g.:
 1N5825 USED ABOVE $I_B \approx 100$ mA
 MSD6100 USED BELOW $I_B \approx 100$ mA

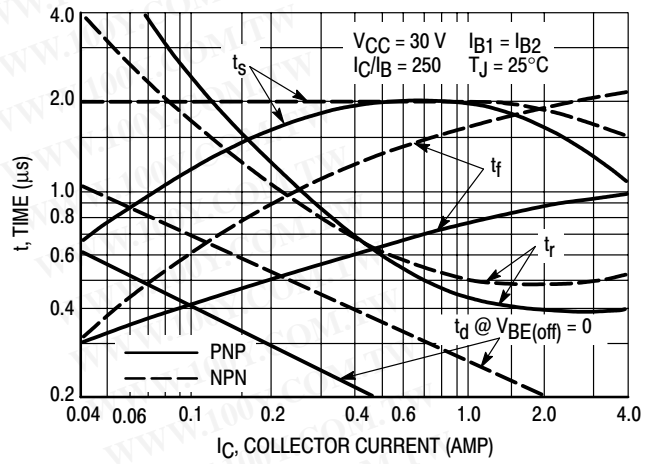
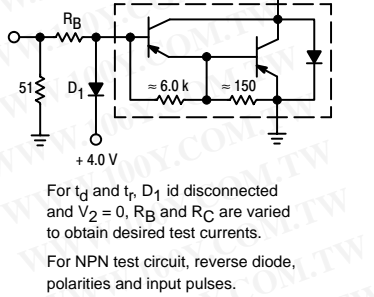
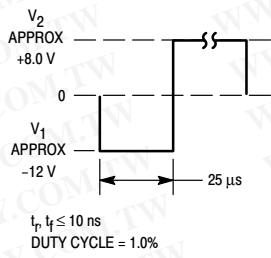


Figure 2. Switching Times Test Circuit

Figure 3. Switching Times

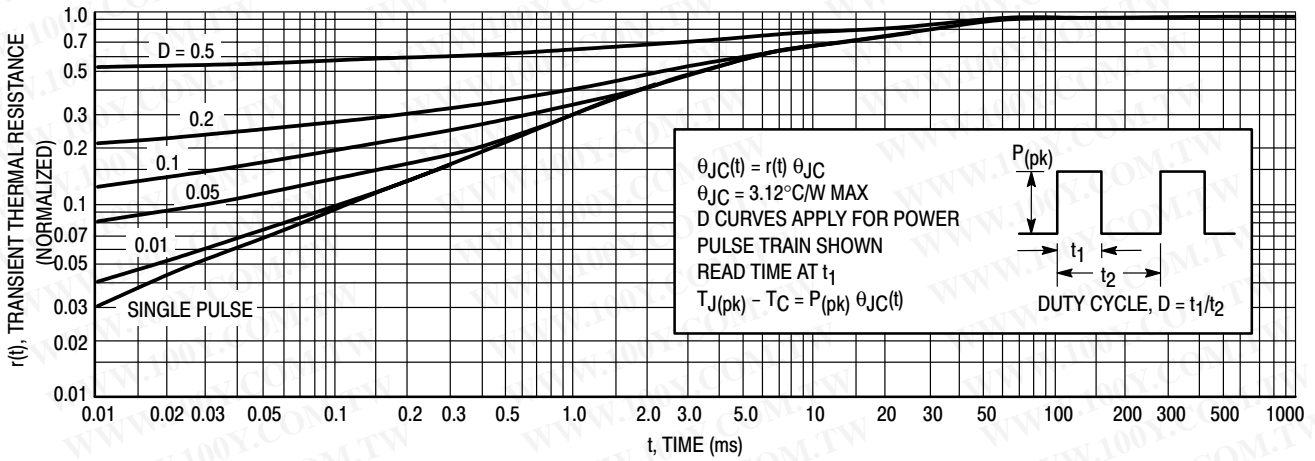


Figure 4. Thermal Response (MJE700, 800 Series)

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

MJE700 MJE702 MJE703 MJE800 MJE802 MJE803

ACTIVE-REGION SAFE-OPERATING AREA

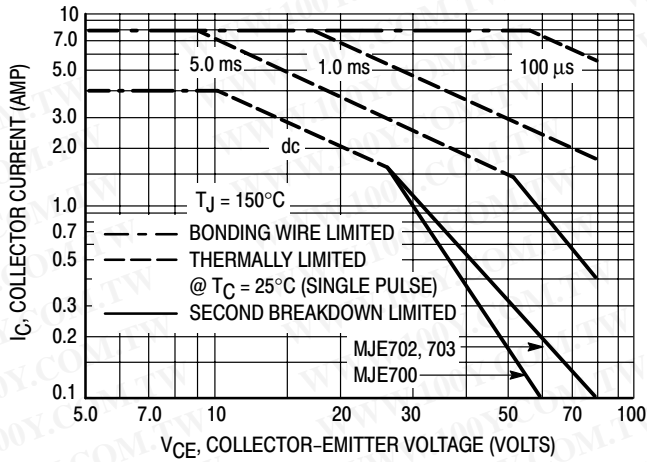


Figure 5. MJE700 Series

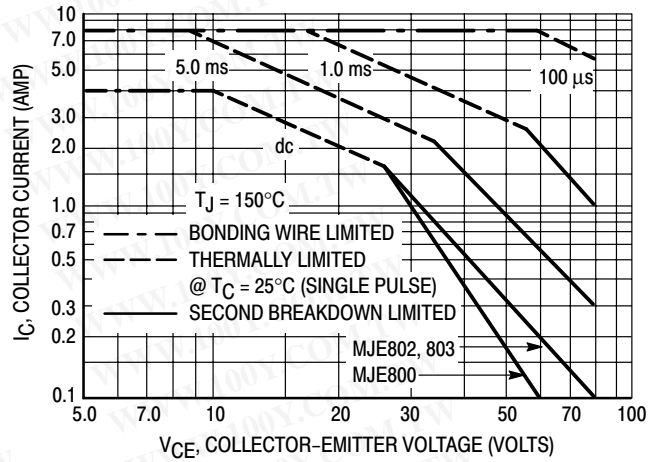


Figure 6. MJE800 Series

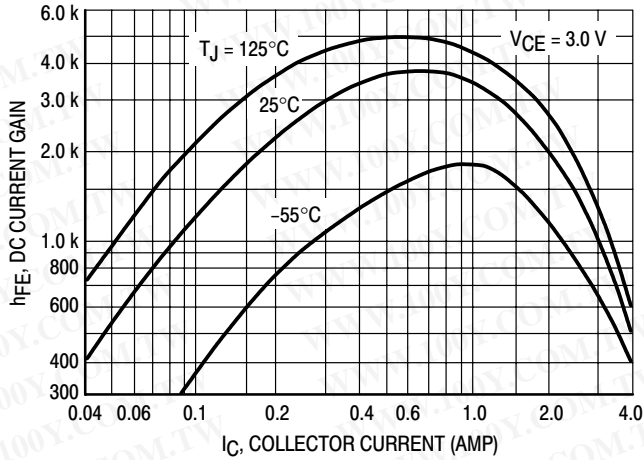
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figures 5 and 6 are based on $T_{J(pk)} = 150^\circ\text{C}$; T_C is variable depending on conditions. Second breakdown

pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} < 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

**PNP
MJE700 Series**



**NPN
MJE800 Series**

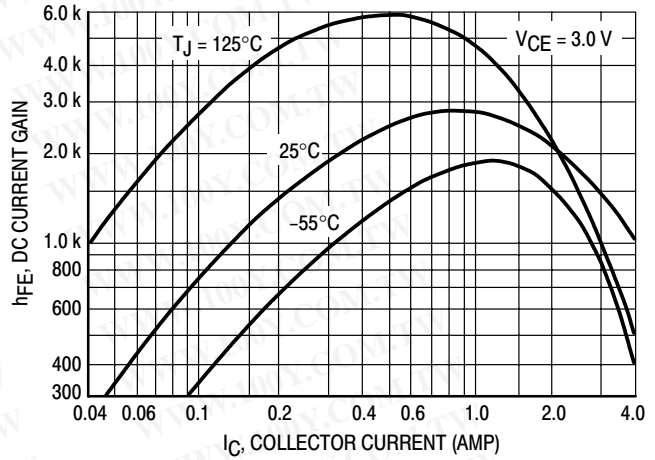


Figure 7. DC Current Gain

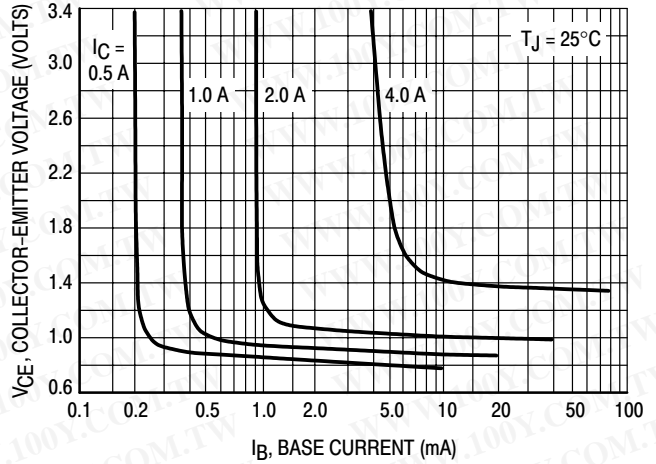
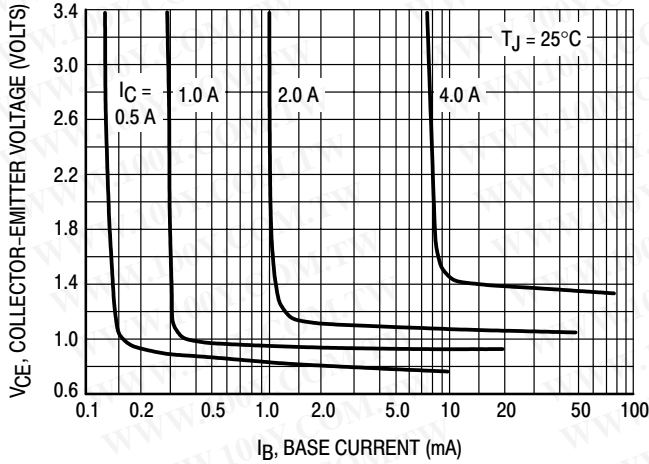


Figure 8. Collector Saturation Region

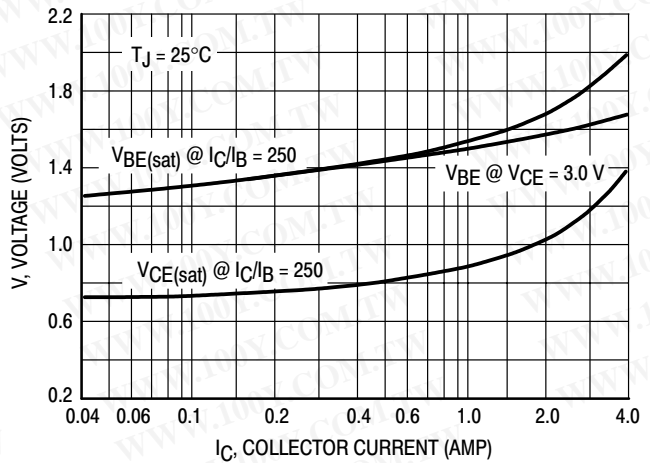
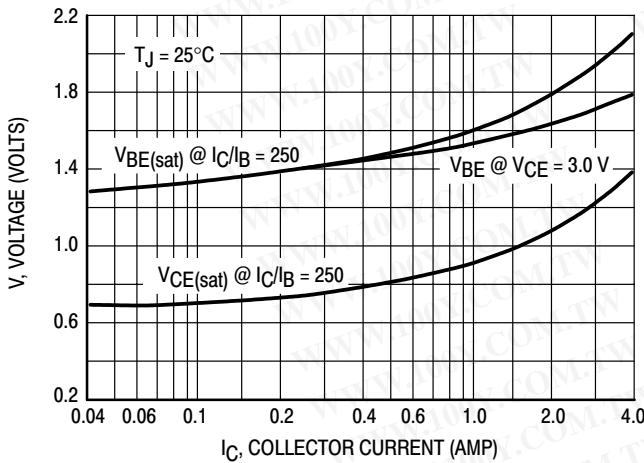
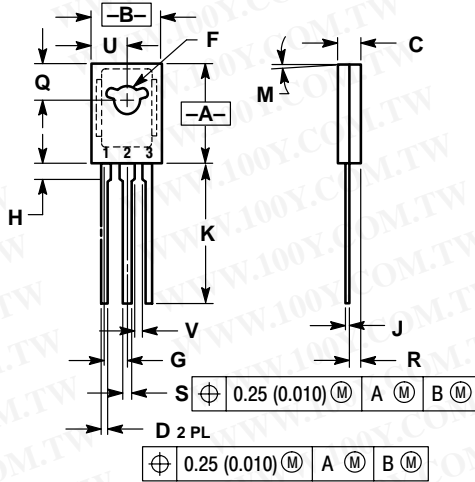


Figure 9. "On" Voltages

MJE700 MJE702 MJE703 MJE800 MJE802 MJE803

PACKAGE DIMENSIONS

TO-225AA
CASE 77-09
ISSUE W



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.425 | 0.435 | 10.80 | 11.04 |
| B | 0.295 | 0.305 | 7.50 | 7.74 |
| C | 0.095 | 0.105 | 2.42 | 2.66 |
| D | 0.020 | 0.026 | 0.51 | 0.66 |
| F | 0.115 | 0.130 | 2.93 | 3.30 |
| G | 0.094 BSC | | 2.39 BSC | |
| H | 0.050 | 0.095 | 1.27 | 2.41 |
| J | 0.015 | 0.025 | 0.39 | 0.63 |
| K | 0.575 | 0.655 | 14.61 | 16.63 |
| M | 5° TYP | | 5° TYP | |
| Q | 0.148 | 0.158 | 3.76 | 4.01 |
| R | 0.045 | 0.065 | 1.15 | 1.65 |
| S | 0.025 | 0.035 | 0.64 | 0.88 |
| U | 0.145 | 0.155 | 3.69 | 3.93 |
| V | 0.040 | --- | 1.02 | --- |

- STYLE 1:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-54151736
勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)